CMOS IC

LC895994

CD-R Encoder/Decoder LSI with Built-in ATAPI (IDE) Interface
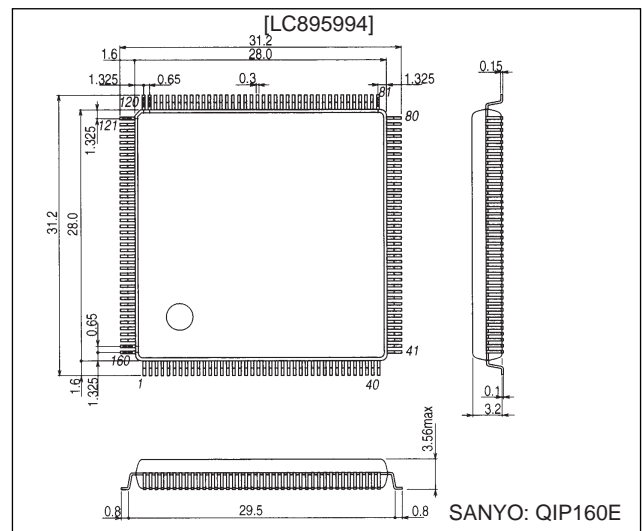
Preliminary

Overview

The LC895994 is a CD-R LSI that provides a wide range of functions including CD-ROM decoding (including ECC) and encoding, subcode Q encoding (CRC addition) and decoding, CD encoding, ATIP decoding and CLV servo, and an IDE interface that includes the register block.

Features

- ECC and EDC correction/addition for the CD-ROM data (during decoding and encoding)
- ATIP decoding and CRC checking for both encoding and decoding
- CLV servo control using ATIP data during encoding
- CIRC code insertion and EFM modulation during encoding
- Support for PCA random EFM output during encoding
- Support for CD-ReWritable (CD-RW) Write Strategy signal output
- Access to buffer RAM from microcontroller via LC895994
- Built-in ATAPI (IDE) interface
- Speeds of 12× for decoding and 4× for encoding
  — Frequencies
    Decoding: 17.2872 MHz
    Encoding: 17.2872 MHz without Write Strategy support
    69.1488 MHz with Write Strategy support
- IDE Transfer rate: 13.3 MB/s when using 16-bit data path 80-ns DRAM chips
- Buffer RAM sizes between 1 and 32 megabits (using 16-bit DRAMs)
- User control over sizes of CD main channel, C2 flag areas in buffer RAM
- Built-in batch transfer function for transferring entire CD main channel, C2 flag, or subcode area in a single operation
- Built-in multiblock transfer function for transferring multiple blocks in a single operation

Package Dimensions

unit: mm

3153A-QFP160E

[LC895994]

SANYO: QIP160E

Specifications

Maximum Ratings at Ta = 25°C, V_{SS} = 0 V

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V_{DD} max		−0.3 to +7.0	V
I/O voltage	V_I, V_O		−0.3 to V_{DD} + 0.3	V
Allowable power dissipation	Pd max	Ta ≤ 70°C	600	mW
Operating temperature	Topr		−30 to +70	°C
Storage temperature	Tstg		−55 to +125	°C
Solder resistance (Pins only)		10 seconds	260	°C

Allowable Operating Range at Ta = −30 to +70°C, V_{SS} = 0 V

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Supply voltage	V_{DD}		4.5	5.0	5.5	V
Input voltage range	V_{IN}		0		V_{DD}	V

DC Characteristics at Ta = −30 to +70°C, V_{SS} = 0 V, V_{DD} = 4.5 to 5.5 V

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Input high-level voltage	V_{IH}	TTL levels, for pin types 1 and 7	2.2			V
Input low-level voltage	V_{IL}				0.8	V
Input high-level voltage	V_{IH}	TTL levels, for pin types 8 and 9, with pull-up resistors	2.2			V
Input low-level voltage	V_{IL}				0.8	V
Input high-level voltage	V_{IH}	TTL levels, for pin types 2 and 10, with Schmitt inputs	2.5			V
Input low-level voltage	V_{IL}				0.6	V
Output high-level voltage	V_{OH}	I_{OH} = −2 mA, for pin type 6	V_{DD} — 2.1			V
Output low-level voltage	V_{OL}	I_{OL} = 2 mA, for pin type 6			0.4	V
Output high-level voltage	V_{OH}	I_{OH} = −24 mA, for pin type 3	V_{DD} — 2.1			V
Output low-level voltage	V_{OL}	I_{OL} = 24 mA, for pin type 3			0.4	V
Output high-level voltage	V_{OH}	I_{OH} = −2 mA, for pin types 4, 7, and 8	V_{DD} — 2.1			V
Output low-level voltage	V_{OL}	I_{OL} = 2 mA, for pin types 4, 7, and 8			0.4	V
Output high-level voltage	V_{OH}	I_{OH} = −24 mA, for pin types 5 and 10	V_{DD} — 2.1			V
Output low-level voltage	V_{OL}	I_{OL} = 24 mA, for pin types 5 and 10			0.4	V
Output low-level voltage	V_{OL}	I_{OL} = 2 mA, for pin type 9.			0.4	V
Input leakage current	I_{IL}	V_I = V_{SS}, V_{DD}, for pin types 1, 2, 7, and 10	−10		+10	μA
Output leakage current		When set to high-impedance output: For pin types 4, 5, 7, and 10.	−10		+10	μA
Pull-up resistance	R_{UP}	For pin types 8 and 9	40	80	160	kΩ

The pin types above refer to the following groups.

Input
(1) SUA0 to SUA7, TEST0 to TEST6, $\overline{RESET}$
(2) BCK, BICLKIN, BIDATAI, C2PO, DA0 to DA2, LOCKIN, LRCK, PLLOUTIN, ROUGH, SBSO, SCOR, SDATA, WFCK, $\overline{CS}$, $\overline{CS1FX}$, CS3FX, $\overline{DIOR}$, $\overline{DIOW}$, $\overline{DMACK}$, $\overline{HRST}$, $\overline{RD}$, $\overline{WR}$
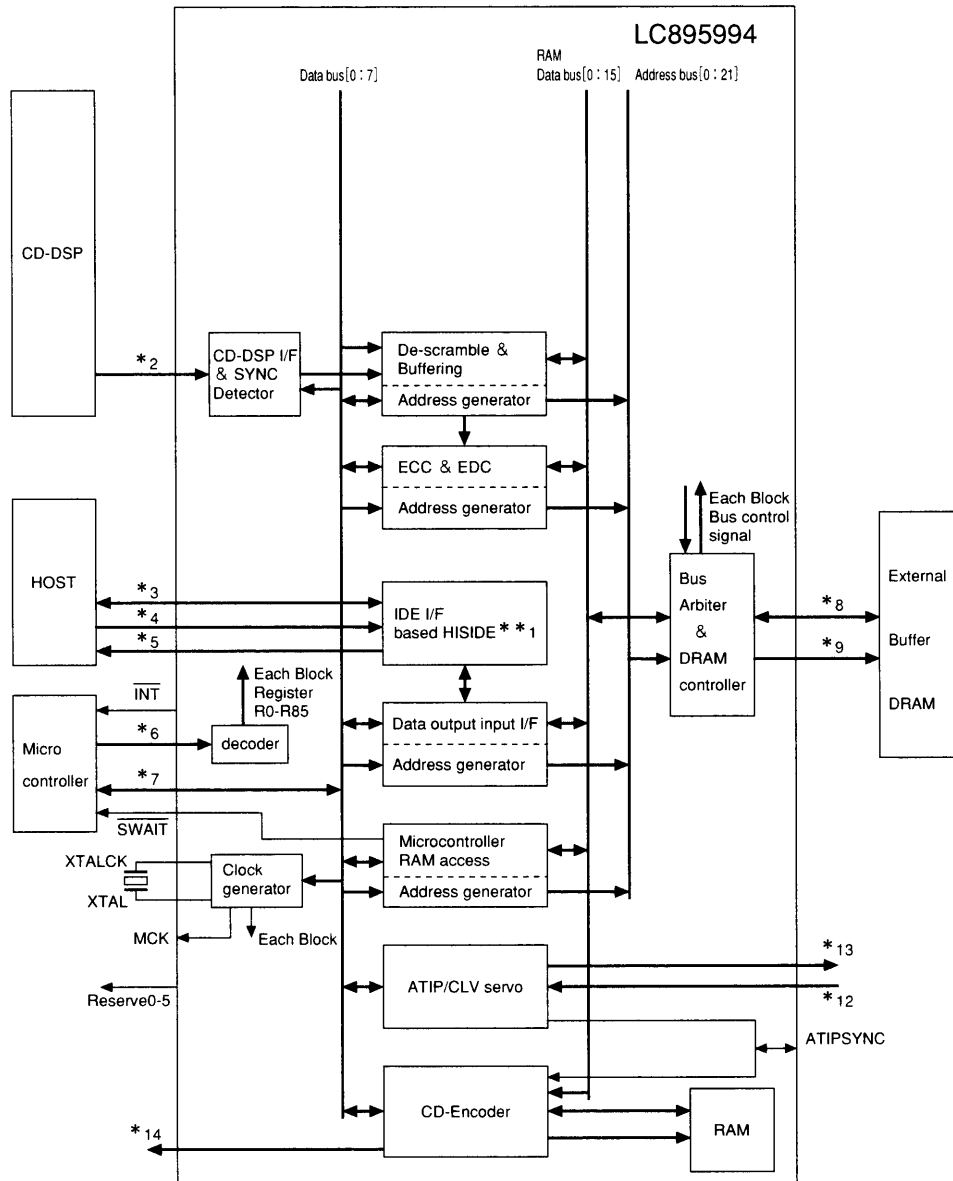
Output
(3) EFM
(4) CLVMDP, CLVMDS, FSW
(5) DMARQ, HINTRQ, IORDY, $\overline{IOCS16}$
(6) DATACKO, EFMG, EFMGATE0 to EFMGATE3, EXCK, LOCK, MCK, MON, PSUBSYNC, RA0 to RA9, SUBSYNC, $\overline{CAS0}$, $\overline{CAS1}$, ERROR, EXTACK, FRCK, $\overline{LWE}$, $\overline{OE}$, $\overline{RAS0}$, $\overline{RAS1}$, $\overline{UWE}$

Input
(7) ATIPSYNC, Reserve0 to Reserve5
(8) D0 to D7, IO0 to IO15
(9) $\overline{INT0}$ to $\overline{INT1}$, $\overline{SWAIT}$
(10) DD0 to DD15, $\overline{DASP}$, $\overline{PDIAG}$

Block Diagram

A10141

*2   BCK, SDATA, LRCK, C2PO

*3   DD0 to DD15, $\overline{\text{DASP}}$, $\overline{\text{PDIAG}}$

*4 $\overline{\text{CS1FX}}$, $\overline{\text{CS3FX}}$, DA0 to DA2, $\overline{\text{DIOR}}$, $\overline{\text{DIOW}}$, $\overline{\text{DMACK}}$

*5   DMARQ, HINTRQ, $\overline{\text{IOCS16}}$, IORDY

*6 $\overline{\text{RD}}$, $\overline{\text{WR}}$, SUA0 to SUA6, $\overline{\text{CS}}$

*7   D0 to D7

*8   IO0 to IO15

*9   RA0 to RA9, $\overline{\text{RAS0}}$, $\overline{\text{RAS1}}$, $\overline{\text{CAS0}}$, $\overline{\text{CAS1}}$, $\overline{\text{OE}}$, $\overline{\text{UWE}}$, $\overline{\text{LWE}}$

*10 PLLOUTIN, ROUGH, LOCKIN, BICLKIN, BIDATAIN

*11 $\overline{\text{ERROR}}$, LOCK, CLV^+ (MDP), CLV^- (MDS), MON, FSW

*12 SUBSYNC, PSUBSYNC, $\overline{\text{FRCK}}$, EFM, EFMG, EFMGATE3 to EFMGATE0, $\overline{\text{EXTACK}}$, $\overline{\text{DATACKO}}$

**1 HISIDE (WD25C32) is made by WESTERN DIGITAL.

LC895994

Pin Descriptions

Pin No.	Pin Name	Type	Description
1	V$_{SS}$	P	
2	Reserve0	O	Reserved for future expansion (Must be left open if unused.)
3	Reserve1	I	Reserved for future expansion (Must be tied to ground if unused.)
4	Reserve2	I	Reserved for future expansion (Must be tied to ground if unused.)
5	TEST1	I	Test pin (connect to V$_{SS}$)
6	XTALCK	I	Crystal oscillator circuit input pin (17.2872 to 69.1488 MHz)
7	XTAL	O	Crystal oscillator circuit output pin
8	TEST2	I	Test pin (connect to V$_{SS}$)
9	MCK	O	Master Clock output pin
10	TEST3	I	Test pin (connect to V$_{SS}$)
11	PSUBSYNC	O	Pseudo-subcode synchronization output
12	$\overline{\text{EXTACK}}$	O	ATIP synchronization acknowledge signal output
13	TEST4	I	Test pin (connect to V$_{SS}$)
14	V$_{DD}$	P	
15	V$_{SS}$	P	
16	CLV+ (MDP)	O	
17	CLV− (MDS)	O	
18	MON	O	CLV servo signal output pins
19	FSW	O	
20	V$_{DD}$	P	
21	V$_{SS}$	P	
22	PLLOUTIN	I	Wobble signal carrier clock input pin
23	ROUGH	I	Rough CLV servo wobble signal input pin
24	LOCKIN	I	CD decoder lock signal input pin
25	LOCK	O	CLV servo lock monitor pin
26	$\overline{\text{ERROR}}$	O	ATIP parity error detection pin
27	ATIPSYNC	B	ATIP synchronization signal I/O pin
28	BIDATAI	I	Biphase data input pin
29	BICLKIN	I	Biphase data transfer clock input pin
30	DATACKO	O	4.3218 MHz (normal speed) oscillator output
31	IO0	B	
32	IO1	B	
33	IO2	B	
34	IO3	B	
35	IO4	B	Data signal pins for ROM encoder/decoder buffer RAM, with pull-up resistors
36	IO5	B	
37	IO6	B	
38	IO7	B	
39	IO8	B	
40	V$_{DD}$	P	
41	V$_{SS}$	P	

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Type: I: Input pin, O: Output pin, B: Bidirectional pin, P: Power supply pin, N: No connection pin

Pin No.	Pin Name	Type	Description
42	IO9	B	Data signal pins for ROM encoder/decoder DRAM, with pull-up resistors
43	IO10	B	
44	IO11	B	
45	IO12	B	
46	IO13	B	
47	IO14	B	
48	IO15	B	
49	V_{SS}	P	
50	RA0	O	Address signal pins for ROM encoder/decoder DRAM
51	RA1	O	
52	RA2	O	
53	RA3	O	
54	RA4	O	
55	RA5	O	
56	RA6	O	
57	RA7	O	
58	RA8	O	
59	RA9	O	
60	V_{DD}	P	
61	V_{SS}	P	
62	$\overline{RAS0}$	O	DRAM $\overline{RAS}$ signal output pins
63	$\overline{RAS1}$	O	
64	$\overline{CAS0}$	O	DRAM $\overline{CAS}$ signal output pins
65	$\overline{CAS1}$	O	
66	$\overline{OE}$	O	DRAM output enable signal output pin
67	$\overline{UWE}$	O	DRAM upper write enable signal output pin
68	$\overline{LWE}$	O	DRAM lower write enable signal output pin
69	TEST0	I	Test pin (connect to V_{SS})
70	V_{DD}	P	
71	EXCK	O	Subcode data read shift clock output pin
72	WFCK	I	Subcode frame synchronization input pin
73	SBSO	I	Subcode serial data input pin
74	SCOR	I	Subcode block synchronization input pin
75	V_{SS}	P	
76	BCK	I	Serial data input clock input pin
77	SDATA	I	Serial data input pin
78	LRCK	I	44.1-kHz strobe signal input pin
79	C2PO	I	C2 pointer input pin
80	V_{DD}	P	
81	V_{SS}	P	
82	$\overline{HRST}$	I	IDE pins
83	$\overline{DASP}$	B	
84	$\overline{CS3FX}$	I	
85	$\overline{CS1FX}$	I	
86	V_{DD}	P	
87	DA2	I	IDE pins
88	DA0	I	
89	$\overline{PDIAG}$	B	

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Pin No.	Pin Name	Type	Description
90	DA1	I	IDE pins
91	$\overline{\text{IOCS16}}$	O	
92	INTRQ	O	
93	V$_{SS}$	P	
94	$\overline{\text{DMACK}}$	I	IDE pins
95	IORDY	O	
96	$\overline{\text{DIOR}}$	I	
97	$\overline{\text{DIOW}}$	I	
98	DMARQ	O	
99	DD15	B	
100	V$_{DD}$	P	
101	V$_{SS}$	P	
102	DD0	B	IDE pins
103	DD14	B	
104	DD1	B	
105	DD13	B	
106	DD2	B	
107	V$_{SS}$	P	
108	DD12	B	IDE pins
109	DD3	B	
110	DD11	B	
111	V$_{SS}$	P	
112	DD4	B	IDE pins
113	DD10	B	
114	DD5	B	
115	V$_{SS}$	P	
116	DD9	B	IDE pins
117	DD6	B	
118	DD8	B	
119	DD7	B	
120	V$_{DD}$	P	
121	V$_{SS}$	P	
122	SUBSYNC	O	Subcode synchronization signal output pin
123	$\overline{\text{FRCK}}$	O	EFM frame synchronization signal output pin
124	EFMG	O	EFM output gate signal output pin
125	EFM	O	EFM signal output pin
126	EFMGATE0	O	EFM pulse width detection gate signals
127	EFMGATE1	O	
128	EFMGATE2	O	
129	EFMGATE3	O	
130	TEST5	I	Test pin (connect to V$_{SS}$)
131	V$_{SS}$	P	
132	TEST6	I	Test pin (connect to V$_{SS}$)

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Pin No.	Pin Name	Type	Description
133	SUA0	I	Command register selection address input pins
134	SUA1	I	
135	SUA2	I	
136	SUA3	I	
137	SUA4	I	
138	SUA5	I	
139	SUA6	I	
140	V_{DD}	P	
141	V_{SS}	P	
142	D0	B	Microcontroller data signal pins, with pull-up resistors
143	D1	B	
144	D2	B	
145	D3	B	
146	D4	B	
147	D5	B	
148	D6	B	
149	D7	B	
150	$\overline{RESET}$	I	Reset pin
151	$\overline{CS}$	I	Chip select signal from microcontroller
152	$\overline{RD}$	I	Data read signal from microcontroller
153	$\overline{WR}$	I	Data write signal from microcontroller
154	$\overline{SWAIT}$	O	Wait signal to microcontroller
155	$\overline{INT0}$	O	Interrupt request signals to microcontroller. Open drain outputs with built-in pull-up resistors.
156	$\overline{INT1}$	O	
157	Reserve3	O	Reserved for future expansion (Must be left open if unused.)
158	Reserve4	O	
159	Reserve5	O	
160	V_{DD}	P	

This catalog provides information as of April, 1998. Specifications and information herein are subject to change without notice.